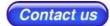


# Series 77, 10 Bit Digital and Series 78 Analog 360° Phase Shifters & Frequency Translators



#### **Application Notes for Microwave Phase Shifter**

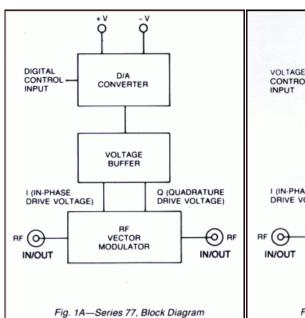
Both Series, 77 and 78, comprise a family of eight solid-state PIN diode phase shifters covering the frequency range from 0.5 to 18 GHz in four bands: 0.5 to 2 GHz, 2 to 6 GHz, 4 to 12 GHz and 6 to 18 GHz. All models provide a full 360° range of phase shift and may also be used for frequency translation applications.

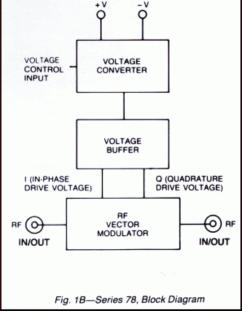
Each unit is an integrated assembly of an RF vector modulator and a driver circuit, consisting of a 10-bit D/A converter and a voltage buffer in the Series 77 digital units (see Fig. 1A) and a voltage converter and buffer in the Series 78 analog configuration (see Fig. 1 B).

The voltage converter in the Series 78 consists of an A/D converter followed by a 10-bit D/A converter, and converts a continuous analog input voltage into discrete steps of 0.35°.

- 0.5 to 18 GHz in four bands:
  - o 0.5 to 2 GHz
  - o 2 to 6 GHz
  - o 4 to 12 GHz
  - o 6 to 18 GHz
- 10 Bit digitally programmable (Series 77)
- Analog control (Series 78)
- High speed
- Guaranteed monotonicity







## **Phase Shift**

Phase shift is achieved utilizing the RF vector modulator approach shown in Fig. 2. The 3 dB hybrid coupler divides the RF signal into two quadrature components which are then modulated in proportion to the sine and cosine of the desired phase shift. The signals are then combined in-phase to yield the phase-shifted output.

Excellent phase accuracy and PM/AM performance (see Figs. 4 and 5) are achieved by using linearized double balanced modulators. In their main

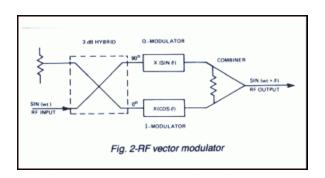


Fig. 3-Series 77 and Series 78 input requirements

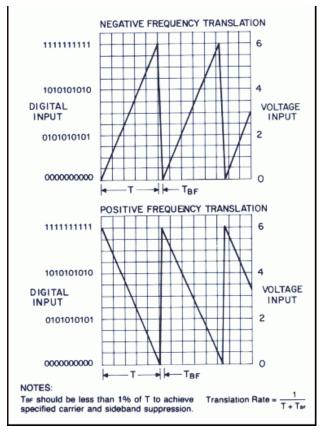
operating bands, phase accuracy is better than  $\pm 10^\circ$  up to 10 GHz and  $\pm 12^\circ$  to 18 GHz. This phase accuracy can be extended to cover the band edges by using a built-in frequency correction circuit. Switching speed is better than 500 nsec.

#### Frequency Translation (Serrodyning)

Special attention in the design of the units has been paid to those characteristics which affect their performance as frequency translators. These include minimizing PM-to-AM conversion, use of high slew rate drivers, and optimizing phase shift linearity with applied signal. As a result, carrier and sideband suppression levels of over 25 and 20 dB, respectively, are obtained in the main bands. The same carrier and sideband performance can be realized over the full stretch band when the internal frequency correction circuit is employed.

See Fig. 3 for input voltage control requirements for Series 77 and 78 when used as a frequency translator.

On special order, frequency translators can be provided for operation over reduced bandwidths with suppression levels of up to 35 dB. Consult the factory for special requirements.



### PERFORMANCE CHARACTERISTICS

#### **SERIES 77**

Control ..... 10 bit TTL **Logic Input** Logic "0" (Bit OFF)..... -0.3 to +0.8V @ 500 μA max Logic "1" (Bit ON)..... +2.0 to +5.0V @ 100 µA max **SERIES 78** Control Voltage ..... 0 to +6V Sensitivity ..... 23.4 mV/LSB Resolution ..... 1.41° Step Uncertainty ..... 0.7° max, 0.3°typ. Input Resistance ..... 2K ohms **COMMON TO BOTH SERIES 77 & 78** +5V at 300mA max +12 to +15V @ 100mA max Power Supply ..... -12 to -15V @ 90mA max **Power Handling Capability Without Performance Degradation** 

+20 dBm

+30 dBm

-30 dBc

0.1°/°C

(+7 dBm for 7720A, 7820)

Survival ......
Harmonics

Phase Variation .....

#### PHASE SHIFTER SPECIFICATIONS

MODEL NOS.	FREQUENCY RANGE (GHz)	INSERTION LOSS (Max.)	VSRW (Max.)	ACCURACY(1) (Max.)	PM/AM (Max.)
7720A & 7820	Main Band 0.7-1.85	11.5 dB	1.75	±10°	±1.1dB
	Stretch Band 0.5-2.0	13.0 dB	1.75	±15°	±2.5dB
7722A & 7822	Main Band 2.6-5.2	10.0 dB	1.6	±10°	±1.1dB
	Stretch Band 2.0-6.0	11.0 dB	1.0	±15°	±1.5dB
7724A & 7824	Main Band 4.5-10.5	10.5 dB	1.8	±10°	±1.1dB
	Stretch Band 4.0-12.0	12.0 dB	1.0	±15°	±2.0dB
7728A & 7828	Main Band 8.0-18.0	12.0 dB	2.0	±12°	±1.25dB
	Stretch Band 6.0-18.0	12.0 UB	2.0	±15°	±2.0dB

#### OTHER SPECIFICATIONS

Switching Speed (50% TTL to within 10° of Final Phase Value): 500 nsec Max.

Minimum phase shift range: Series 77: 360° in 1024 Steps (10 -bit) Series 78:360° @ 60°/volt

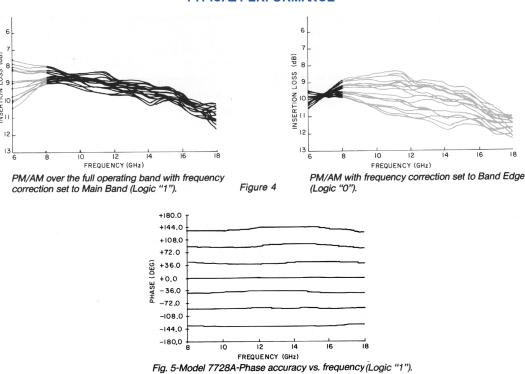
#### FREQUENCY TRANSLATOR SPECIFICATIONS

TRANSLATION RATE (min.)	CARRIER (1) SUPRESSION (min.)	SIDE BAND (1) SUPRESSION (Min)	INTERATION LOSS VARIATION (Max.) with translation rate:
0 to 500 kHz <sup>(2)</sup>	Main Band: 25dB Stretch Band: 18dB	Main Band: 20dB Stretch Band: 15 dB	200kHz: 1dB 500kHz: 3dB

#### NOTES:

- (1) When operating as a Phase Shifter outside the Main Band Frequency Range, a TTL Low (0) applied to the J3 Power/Control Connector Freq. Correction Pin (pin 3) will result in band edge frequencies exhibiting enhanced performance characteristics. The resultant Insertion Loss, Accuracy and PM/AM specifications will be the same as those shown for the Main Band Frequency Range. When using the unit as a Frequency Translator, similar enhanced performance can be achieved for Carrier & Sideband Suppression.
- (2) All specifications are met using five or more most significant bits for 0 to 200 kHz translation rates. For 201-500 kHz translation rates, only the four most significant bits are used.
- (3) Specifications for the Stretch Band are typical.

### TYPICAL PERFORMANCE



#### **ENVIRONMENTAL RATINGS**

#### **ACCESSORIES FURNISHED**

Operating Temperature
Range......-54° to + 100°C

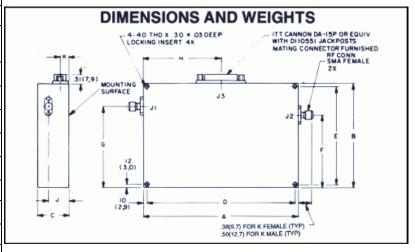
Mating power/control connector

AVAILABLE OPTIONS

Non-Operating

Temperature Range	-65° to + 125° C	Option no.	Description
Humidity	MIL-STD-202F, Method 103B,	7	Two SMA male rf connectors
	Cond. B (96 hrs at 95%)		
Shock	MIL-STD-202F, Method 213B, Cond. B (75 G, 6 msec)	10	One SMA male (J2) and one SMA female (J1) rf connector
Vibration	MIL-STD-202F, Method 204D, Cond. B (.06" double amplitude or 15G, whichever is less)		
Altitude	MIL-STD-202F, Method 105C Cond. B (50,000 ft.)		
Temp. Cycling	MIL-STD-202F, Method 107D Cond.		

A, 5 cycles								
J3 PIN FUNCTIONS								
PIN	FUNCTION							
No.	SERIES 77 (1)	SERIES 78						
1	-12 V to -15 V	-12 V to -15 V						
2	+12 V to +15 V	+12 V to +15 V						
3	Freq.Correction Circuit Select <sup>(3)</sup> "0" = Band Edge	Freq.Correction Circuit Select "0" = BandEdge						
4	1.4° <sup>(3)</sup>	Not Used						
5	5.6° <sup>(3)</sup>	Not Used						
6	45.0° <sup>(3)</sup>	Not Used						
7	180.0° (MSB) <sup>(3)</sup>	Not Used						
8	90.0° <sup>(3)</sup>	Not Used						
9	Ground	Ground (Sig)						
10	0.7°(3)	Ground (Pwr)						
11	22.5°	Not Used						
12	2.8°	Not Used						
13	11.3°	Not Used						
14	0.35° (LSB)	Control Voltage						
15	+5V ±0.5V DC <sup>(2)</sup>	+5V						



## Note:

- Unused logic bit must be grounded.
   Must not exceed +7VDC See footnote(3) below.
- 3. Must not be greater than +0.3VDC above voltage at pin 15.

MODEL	Α	В	С	D	E	F	G	Н	J	K	WEIGHT(APPROX)
7720A	4.95 ±	3.38 ±.03(85,9)	1.02(25,9)	4.75 ±.01(120,7)	3.12 ± .01(79,2)	2.62(66,5)	1.69(42,9)	2.48(62,9)	.73(18,5)	32(8,1)	13 oz. (369 gm)
7820			1.48 (37,6)						1.18 (30,0)	.78(19,8)	15 oz. (425 gm)
7722A		3.25 ± .03(82,6)	.84(21.3)	3.05 ± 3 .01(77,5) .0		1.63(41,4)	1.99(50,5)	1.63(41,4)	.66(16,8)	.32(8,1)	9 oz. (255 gm)
7822	3.25 ±		1.25(31,8)		3.00 ± .01(76,2)				1.07(27,2)	.72(18,3)	10 oz. (284 gm)
7724A	.03(82,6)		.84(21.3)				1.83(46,5)		.66(16,8)	.32(8,1)	9 oz. (255 gm)
7824			1.25(31,8)						1.07(27,2)	.72(18,3)	10 oz. (284 gm)
7728A	2.50 ± .03(63,5)	3.00 ±.03(76,2)	.88(22,4)	2.30 2.75	2.75		0(38,1) 1.63(41,4)	1.25(31,8)	.71(18,0)	.39(9,9)	6 oz. (170 gm)
7878			1.19(30,2)		±0.1(69,9)	1.50(38,1)			1.02(25,9)	.69(17,6)	8 oz. (227 gm)

Dimensional Tolerances, unless otherwise indicated: .XX±.02; .XXX±.005



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